

MITSUBISHI THYRISTOR MODULES  
**TM55DZ/CZ-24,-2H**  
 HIGH VOLTAGE HIGH POWER GENERAL USE  
 INSULATED TYPE

TM55DZ/CZ-24,-2H



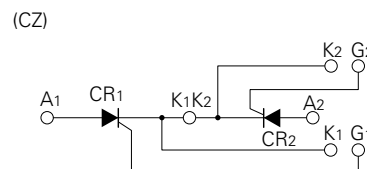
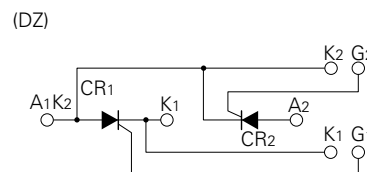
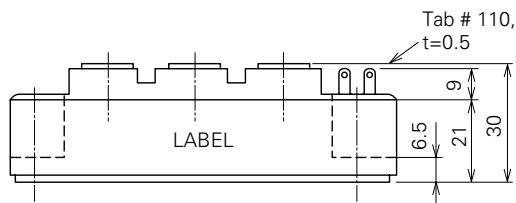
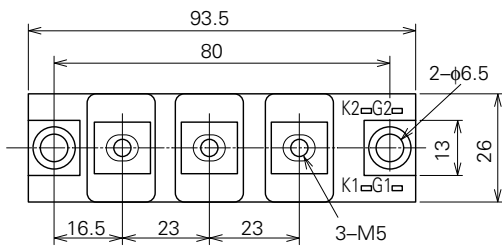
- **IT (AV)** Average on-state current ..... **55A**
- **VRRM** Repetitive peak reverse voltage  
 ..... **1200/1600V**
- **VDRM** Repetitive peak off-state voltage  
 ..... **1200/1600V**
- **DOUBLE ARMS**
- **Insulated Type**
- **UL Recognized**  
 Yellow Card No. E80276 (N)  
 File No. E80271

**APPLICATION**

DC motor control, NC equipment, AC motor control, Contactless switches,  
 Electric furnace temperature control, Light dimmers

**OUTLINE DRAWING & CIRCUIT DIAGRAM**

Dimensions in mm



**TM55DZ/CZ-24,-2H**

**HIGH VOLTAGE HIGH POWER GENERAL USE  
INSULATED TYPE**

**ABSOLUTE MAXIMUM RATINGS**

| Symbol  | Parameter                             | Voltage class |      | Unit |
|---------|---------------------------------------|---------------|------|------|
|         |                                       | 24            | 2H   |      |
| VRRM    | Repetitive peak reverse voltage       | 1200          | 1600 | V    |
| VRSM    | Non-repetitive peak reverse voltage   | 1350          | 1700 | V    |
| VR (DC) | DC reverse voltage                    | 960           | 1280 | V    |
| VDRM    | Repetitive peak off-state voltage     | 1200          | 1600 | V    |
| VDSM    | Non-repetitive peak off-state voltage | 1350          | 1700 | V    |
| VD (DC) | DC off-state voltage                  | 960           | 1280 | V    |

| Symbol           | Parameter                                 | Conditions  | Ratings               | Unit             |
|------------------|---|---|-----------------------|------------------|
| IT (RMS)         | RMS on-state current                      |   | 86                    | A                |
| IT (AV)          | Average on-state current                  | Single-phase, half-wave 180° conduction, Tc=81°C                                  | 55                    | A                |
| ITSM             | Surge (non-repetitive) on-state current   | One half cycle at 60Hz, peak value  | 1100                  | A                |
| I <sup>2</sup> t | I <sup>2</sup> t for fusing               | Value for one cycle of surge current  | 5.0 × 10 <sup>3</sup> | A <sup>2</sup> s |
| di/dt            | Critical rate of rise of on-state current | V <sub>D</sub> =1/2V <sub>DRM</sub> , I <sub>G</sub> =1.0A, T <sub>j</sub> =125°C | 100                   | A/μs             |
| PGM              | Peak gate power dissipation               |   | 5.0                   | W                |
| PG (AV)          | Average gate power dissipation            |   | 0.5                   | W                |
| VFGM             | Peak gate forward voltage                 |   | 10                    | V                |
| VRGM             | Peak gate reverse voltage                 |   | 5.0                   | V                |
| IFGM             | Peak gate forward current                 |   | 2.0                   | A                |
| T <sub>j</sub>   | Junction temperature                      |   | -40~+125              | °C               |
| T <sub>stg</sub> | Storage temperature                       |   | -40~+125              | °C               |
| V <sub>iso</sub> | Isolation voltage                         | Charged part to case  | 2500                  | V                |
| —                | Mounting torque                           | Main terminal screw M5  | 1.47~1.96             | N·m              |
|                  |   |   | 15~20                 | kg·cm            |
|                  |   | Mounting screw M6   | 1.96~2.94             | N·m              |
|                  |   |   | 20~30                 | kg·cm            |
| —                | Weight                                    | Typical value   | 160                   | g                |

**ELECTRICAL CHARACTERISTICS**

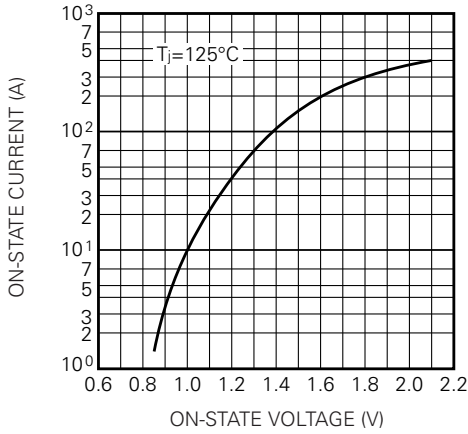
| Symbol                | Parameter                                  | Test conditions   | Limits |      |      | Unit |
|-----------------------|--|---|--------|------|------|------|
|                       |  |   | Min.   | Typ. | Max. |      |
| IRRM                  | Repetitive peak reverse current            | T <sub>j</sub> =125°C, VRRM applied                               | —      | —    | 10   | mA   |
| IDRM                  | Repetitive peak off-state current          | T <sub>j</sub> =125°C, VDRM applied                               | —      | —    | 10   | mA   |
| V <sub>TM</sub>       | On-state voltage                           | T <sub>j</sub> =125°C, I <sub>TM</sub> =165A, instantaneous meas. | —      | —    | 1.5  | V    |
| dv/dt                 | Critical rate of rise of off-state voltage | T <sub>j</sub> =125°C, V <sub>D</sub> =2/3V <sub>DRM</sub>        | 500    | —    | —    | V/μs |
| V <sub>GT</sub>       | Gate trigger voltage                       | T <sub>j</sub> =25°C, V <sub>D</sub> =6V, R <sub>L</sub> =2Ω      | —      | —    | 2.0  | V    |
| V <sub>GD</sub>       | Gate non-trigger voltage                   | T <sub>j</sub> =125°C, V <sub>D</sub> =1/2V <sub>DRM</sub>        | 0.25   | —    | —    | V    |
| I <sub>GT</sub>       | Gate trigger current                       | T <sub>j</sub> =25°C, V <sub>D</sub> =6V, R <sub>L</sub> =2Ω      | 15     | —    | 100  | mA   |
| R <sub>th (j-c)</sub> | Thermal resistance                         | Junction to case (per 1/2 module)                                 | —      | —    | 0.5  | °C/W |
| R <sub>th (c-f)</sub> | Contact thermal resistance                 | Case to fin, conductive grease applied (per 1/2 module)           | —      | —    | 0.2  | °C/W |
| —                     | Insulation resistance                      | Measured with a 500V megohmmeter between main terminal and case   | 10     | —    | —    | MΩ   |

# TM55DZ/CZ-24,-2H

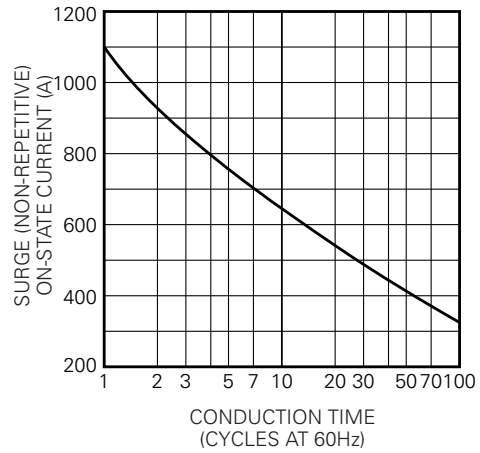
HIGH VOLTAGE HIGH POWER GENERAL USE  
INSULATED TYPE

## PERFORMANCE CURVES

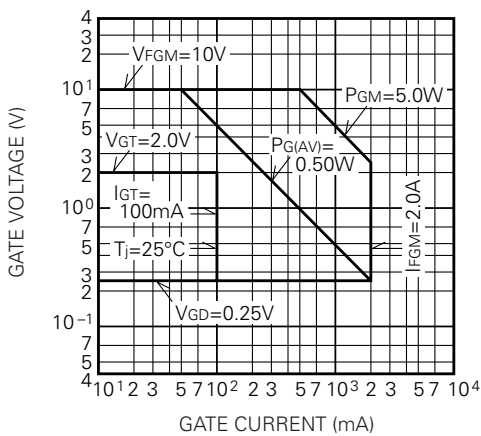
MAXIMUM ON-STATE CHARACTERISTIC



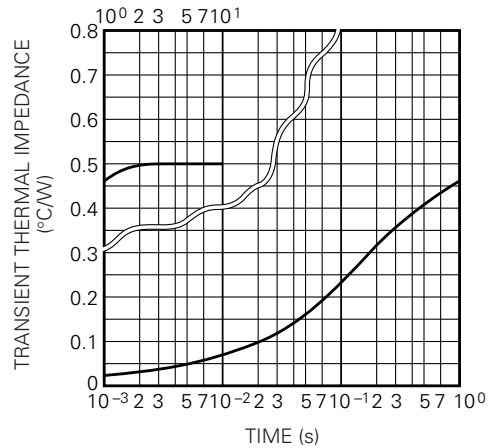
RATED SURGE (NON-REPETITIVE) ON-STATE CURRENT



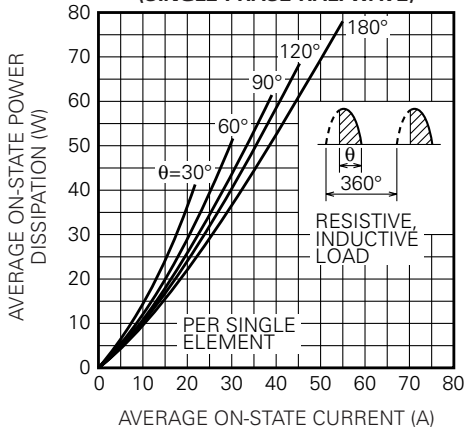
GATE CHARACTERISTICS



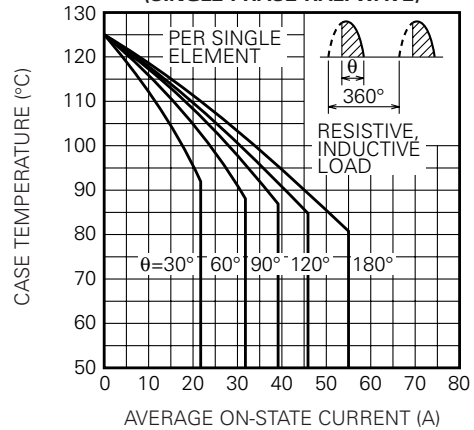
MAXIMUM TRANSIENT THERMAL IMPEDANCE (JUNCTION TO CASE)



MAXIMUM AVERAGE ON-STATE POWER DISSIPATION (SINGLE PHASE HALF WAVE)

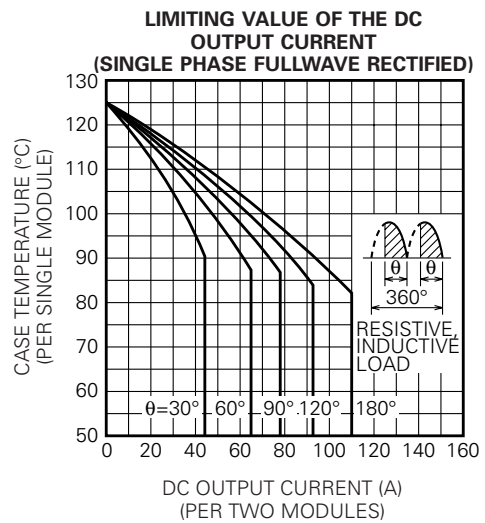
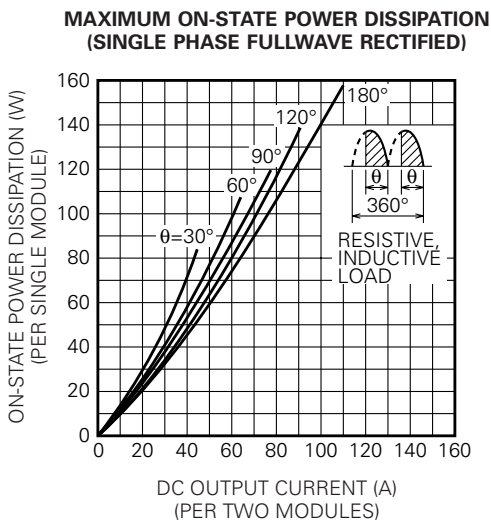
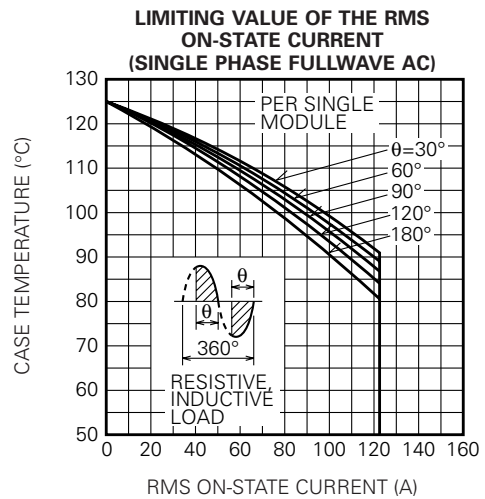
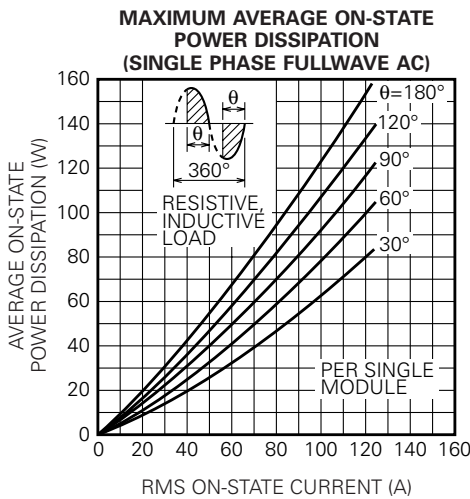
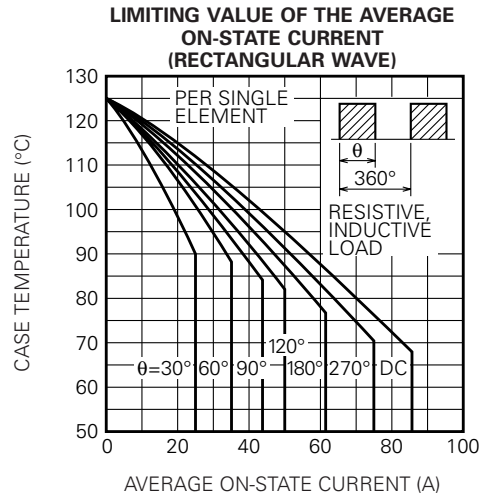
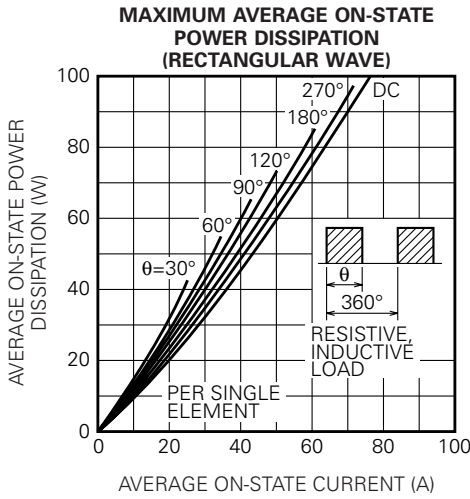


LIMITING VALUE OF THE AVERAGE ON-STATE CURRENT (SINGLE PHASE HALF WAVE)



TM55DZ/CZ-24,-2H

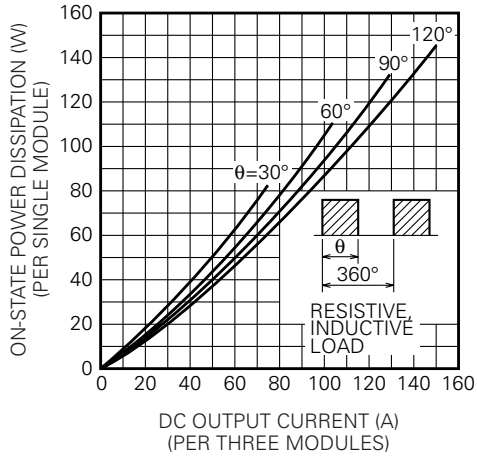
HIGH VOLTAGE HIGH POWER GENERAL USE  
INSULATED TYPE



**TM55DZ/CZ-24,-2H**

HIGH VOLTAGE HIGH POWER GENERAL USE  
INSULATED TYPE

**MAXIMUM ON-STATE POWER DISSIPATION  
(THREE PHASE FULLWAVE RECTIFIED)**



**LIMITING VALUE OF THE DC  
OUTPUT CURRENT  
(THREE PHASE FULLWAVE RECTIFIED)**

